



MICROCIRCUIT DATA SHEET

MN54ABT574-X REV 0B0

Original Creation Date: 11/29/94
Last Update Date: 10/14/98
Last Major Revision Date: 03/19/97

OCTAL D-TYPE FLIP-FLOP WITH 3-STATE OUTPUTS

General Description

The ABT574 is a high-speed, low power octal D-type flip-flop with a buffered common Clock(CP) and a buffered common Output Enable(OE). The information presented to the D inputs is stored in the flip-flops on the LOW-to-HIGH Clock(CP) transistion. The device is functionally identical to the 54ABT374 except for the pinouts.

Industry Part Number

54ABT574

NS Part Numbers

54ABT574E-QML *
54ABT574J-QML **
54ABT574W-QML ***

Prime Die

NB574

Controlling Document

See Features Page

Processing

MIL-STD-883, Method 5004

Quality Conformance Inspection

MIL-STD-883, Method 5005

Subgrp	Description	Temp (°C)
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1	Static tests at	+25
2	Static tests at	+125
3	Static tests at	-55
4	Dynamic tests at	+25
5	Dynamic tests at	+125
6	Dynamic tests at	-55
7	Functional tests at	+25
8A	Functional tests at	+125
8B	Functional tests at	-55
9	Switching tests at	+25
10	Switching tests at	+125
11	Switching tests at	-55

Features

- Inputs and outputs on opposite sides of package allowing easy interface with microprocessors
- Useful as input or output port for microprocessors
- TRI-STATE outputs for bus-oriented applications
- Output sink capability of 48mA, source capability of 24 mA
- Guaranteed latchup protection
- High impedance glitch free bus loading during entire power up and power down cycle.
- Non-Destructive hot insertion capability.
- SMD : 5962-9322001Q2A*, QRA**, QSA***

(Absolute Maximum Ratings)

(Note 1)

Vcc Pin Potential to Ground Potential	-0.5V to +7.0V
Input Voltage (Note 2)	-0.5V to +7.0V
Input Current (Note 2)	-30mA to +5.0mA
Voltage Applied To Any Output In the Disabled or Power-Off State In The High State	-0.5V to 5.5V -0.5V to Vcc
Current Applied To Output In The Low State (Max)	96mA
Junction Temperature (Tj) Ceramic	+175C
Thermal Resistance Junction-To-Case (Theta JC)	See Mil-Std 1835
Storage Temperature	-65C to +150C
Lead Temperature (Soldering, 10 seconds)	+300C
ESD Classification	Class 3
Maximum Power Dissipation	500 mW

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

Recommended Operating Conditions

Supply Voltage (Vcc)	4.5V to 5.5V
Operating Temperature	-55C to +125C
Minimum Input Edge Rate (dV/dt)	
Data Input	50 mV/ns
Enable Input	20 mV/ns
Clock Input	100mV/ns
Maximum Output Current	
High Level (Ioh)	-24 mA
Low Level (Iol)	48 mA

Electrical Characteristics

DC PARAMETERS

(The following conditions apply to all the following parameters, unless otherwise specified.)

DC: 4.5V to 5.5V Temp Range: -55C to 125C

SYMBOL	PARAMETER	CONDITIONS	NOTES	PIN-NAME	MIN	MAX	UNIT	SUB-GROUPS
ICCH	Supply Current	VCC=5.5V, VINH=5.5V, VINL=0.0V	1, 4	VCC		250.0	uA	1, 2, 3
ICCL	Supply Current	VCC=5.5V, VINH=5.5V, VINL=0.0V	1, 4	VCC		30.0	mA	1, 2, 3
IC CZ	Supply Current	VCC=5.5V, VINH=5.5V, VINL=0.0V	1, 4	VCC		250.0	uA	1, 2, 3
ICCT	Supply Current per Input	VCC=5.5V, OE=0.0V Input under test=3.4V Other inputs=5.5V or 0.0V	1, 4	VCC		2.5	mA	1, 2, 3
		VCC=5.5V, OE=3.4V Other inputs=5.5V or 0.0V	1, 4	VCC		2.5	mA	1, 2, 3
IIH	High Level Input Current	VCC=5.5V, VINH=5.5V	1, 4	IN		2.0	uA	1, 2, 3
IIL	Low Level Input Current	VCC=5.5V, VINL=0.0V	1, 4	IN		-2.0	uA	1, 2, 3
IOZH	Maximum TRI-STATE Leakage Current HIGH	VCC=5.5V, VOUT=2.7V VINL=0.0V, VIH (OE)=2.0V	1, 4	OUT		10.0	uA	1, 2, 3
IOZL	Maximum TRI-STATE Leakage Current LOW	VCC=5.5V, VOUT=0.5V VINH=5.5V, VIH (OE)=2.0V	1, 4	OUT		-10.0	uA	1, 2, 3
ICEX	Output High Leakage Current	VCC=5.5V, VOUT=5.5V VINH=5.5V	1, 4	OUT		50.0	uA	1, 2, 3
IOS	Output Short Circuit Current	VCC=5.5V, VOUT=0.0V VINH=5.5V	1, 4, 10	OUT	-100	-275	mA	1, 2, 3
IOS1	Output Short Circuit Current	VCC=5.5V, VOUT=2.5V VINH=5.5V	1, 4, 10	OUT	-50	-180	mA	1, 2, 3
IBVI	Input High Current Breakdown Test	VCC=5.5V, VINH=7.0V	1, 4	IN		7.0	uA	1, 2, 3
IZZ	Bus Drainage Test	VCC=0.0V, VOUT=4.5V, VINL=0.0V	1, 4	IN/OUT	-100	100	uA	1, 2, 3
VOL	Low Level Output Voltage	VCC=4.5V, IOL=48.0mA, VINH=4.5V, VINL=0.0V, VIH=2.0V, VIL=0.8V	1, 4	OUT		0.55	V	1, 2, 3
VOH	High Level Output Voltage	VCC=4.5V, IOH=-24.0mA, VINH=4.5V, VINL=0.0V, VIH=2.0V, VIL=0.8V	1, 4	OUT	2.0		V	1, 2, 3
		VCC=4.5V, IOH=-3mA, VINH=4.5V, VINL=0.0V, VIH=2.0V, VIL=0.8V	1, 4	OUT	2.5		V	1, 2, 3
		VCC=5.0V, IOH=-3mA, VINH=5.0V, VINL=0.0V, VIH=2.0V, VIL=0.8V	1, 4	OUT	3.0		V	1, 2, 3

Electrical Characteristics

DC PARAMETERS(Continued)

(The following conditions apply to all the following parameters, unless otherwise specified.)
DC: 4.5V to 5.5V Temp Range: -55C to 125C

SYMBOL	PARAMETER	CONDITIONS	NOTES	PIN-NAME	MIN	MAX	UNIT	SUB-GROUPS
VID	Input Leakage Test	VCC=0.0V, IID=1.9uA, VINL=0.0V	1, 4	IN	4.75		V	1, 2, 3
VCD	Input Clamp Diode Voltage	VCC=4.5V, IKL=-18mA, VINH=4.5V, VINL=0.0V	1, 4	IN		-1.2	V	1, 2, 3
VOLP	Low Level Ground Bounce	VCC=5.0V, LOAD : 50pF / 500 OHMS	7, 8	OUT		0.8	V	4
VOLV	Low Level Ground Bounce	VCC=5.0V, LOAD : 50pF / 500 OHMS	7, 8	OUT		-1.7	V	4
VOHP	High Level VCC Bounce	VCC=5.0V, LOAD : 50pF / 500 OHMS	7, 8	OUT		1.3	V	4
VOHV	High Level VCC Bounce	VCC=5.0V, LOAD : 50pF / 500 OHMS	7, 8	OUT		-0.8	V	4
CIN	Input Capacitance	VCC=0.0V	7	IN		8.5	pF	4
COUT	Output Capacitance	VCC=5.0V	7	OUT		14.5	pF	4

Electrical Characteristics

AC PARAMETERS

(The following conditions apply to all the following parameters, unless otherwise specified.)
AC: CL=50pF RL=500 OHMS TRISE/TFALL = 3.0ns

SYMBOL	PARAMETER	CONDITIONS	NOTES	PIN-NAME	MIN	MAX	UNIT	SUB-GROUPS
tpLH	Propagation Delay	VCC=5.0V @25C, VCC=4.5V & 5.5V @-55C/125C	2, 5	CP to On	1.5	6.2	ns	9
			2, 5	CP to On	1.5	7.0	ns	10, 11
tpHL	Propagation Delay	VCC=5.0V @25C, VCC=4.5V & 5.5V @-55C/125C	2, 5	CP to On	1.5	7.0	ns	9
			2, 5	CP to On	1.5	7.4	ns	10, 11
tpZL	Output Enable Time	VCC=5.0V @25C, VCC=4.5V & 5.5V @-55C/125C	2, 5	OE to On	1.0	5.9	ns	9
			2, 5	OE to On	1.0	7.2	ns	10, 11
tpZH	Output Enable Time	VCC=5.0V @25C, VCC=4.5V & 5.5V @-55C/125C	2, 5	OE to On	1.0	5.5	ns	9
			2, 5	OE to On	1.0	6.5	ns	10, 11
tpHZ	Output Disable Time	VCC=5.0V @25C, VCC=4.5V & 5.5V @-55C/125C	2, 5	OE to On	1.0	6.2	ns	9
			2, 5	OE to On	1.0	7.2	ns	10, 11
tpLZ	Output Disable Time	VCC=5.0V @25C, VCC=4.5V & 5.5V @-55C/125C	2, 5	OE to On	1.0	5.8	ns	9
			2, 5	OE to On	1.0	6.7	ns	10, 11
ts(H)	Setup Time (HIGH)	VCC=5.0V @25C, VCC=4.5V & 5.5V @-55C/125C	7	Dn - CP	1.5		ns	9, 10, 11
ts(L)	Setup Time (LOW)	VCC=5.0V @25C, VCC=4.5V & 5.5V @-55C/125C	7	Dn - CP	2.0		ns	9, 10, 11
th(H/L)	Hold Time HIGH or LOW	VCC=5.0V @25C, VCC=4.5V & 5.5V @-55C/125C	7	Dn - CP	2.0		ns	9, 10, 11
tw(H/L)	Pulse Width	VCC=5.0V @25C, VCC=4.5V & 5.5V @-55C/125C	7	CP	3.3		ns	9, 10, 11
Fmax	Maximum Clock Frequency	VCC=5.0V @25C, VCC=4.5V & 5.5V @-55C/125C	7	CP	150		MHz	9, 10, 11

Note 1: SCREEN TESTED 100% ON EACH DEVICE AT -55C, +25C & +125C TEMP., SUBGROUPS 1,2,3,7 & 8.

Note 2: SCREEN TESTED 100% ON EACH DEVICE AT -55C, +25C & +125C TEMP., SUBGROUPS A9, A10 & A11.

Note 3: SCREEN TESTED 100% ON EACH DEVICE AT +25C TEMP. ONLY, SUBGROUP 9.

Note 4: SAMPLE TESTED (METHOD 5005, TABLE 1) ON EACH MFG. LOT AT +25C, +125C & -55C TEMP., SUBGROUPS A1, 2, 3, 7 & 8.

Note 5: SAMPLE TESTED (METHOD 5005, TABLE 1) ON EACH MFG. LOT AT +25C, +125C & -55C TEMP., SUBGROUPS A9, 10, 11.

(Continued)

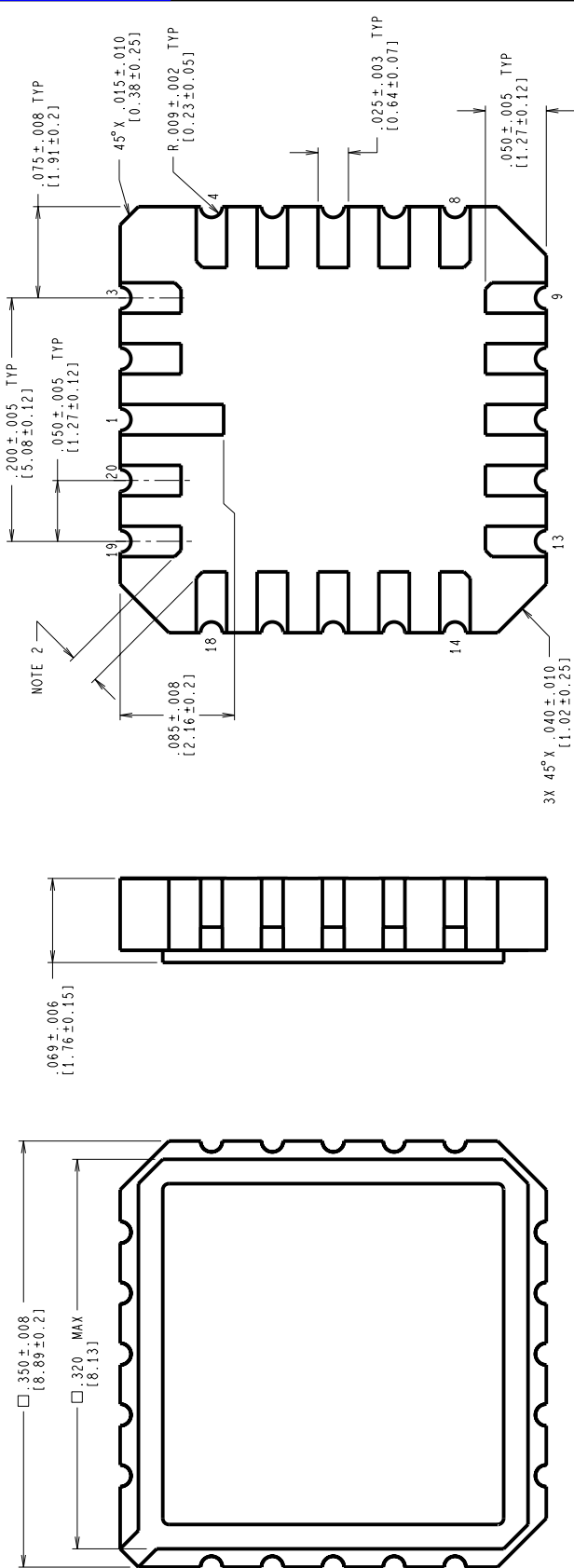
- Note 6: SAMPLE TESTED (METHOD 5005, TABLE 1) ON EACH MFG. LOT AT +25C TEMP. ONLY, SUBGROUP A9.
- Note 7: NOT TESTED (GUARANTEED BY DESIGN CHARACTERIZATION DATA).
- Note 8: MAX NUMBER OF OUTPUTS DEFINED AS (N). N-1 DATA INPUTS ARE DRIVEN 0V TO 3.0V. ONE OUTPUT AT @ VOL OR @ VOH.
- Note 9: MAX NUMBER OF DATA INPUTS (N) SWITCHING. (N-1) INPUTS SWITCHING 0V TO 3.0V. INPUT-UNDERTEST SWITCHING: 3V TO THRESHOLD (VILD), 0V TO THRESHOLD (VIHD), FREQ.= 1 MHZ.
- Note 10: MAXIMUM TEST DURATION NOT TO EXCEED ONE SECOND, NOT MORE THAN ONE OUTPUT SHORTED AT ONE TIME.

Graphics and Diagrams

GRAPHICS#	DESCRIPTION
E20ARE	LCC (E), TYPE C, 20 TERMINAL (P/P DWG)
J20ARM	CERDIP (J), 20 LEAD (P/P DWG)
P000025A	(new)
P000026A	(new)
W20ARF	CERPACK (W), 20 LEAD (P/P DWG)

See attached graphics following this page.

REVISIONS			
LTR	DESCRIPTION	E.C.N.	DATE
E	REVISE AND REDRAW	10005	02/10/94
			DEG/



CONTROLLING DIMENSION IS INCH
VALUES IN [] ARE MILLIMETERS

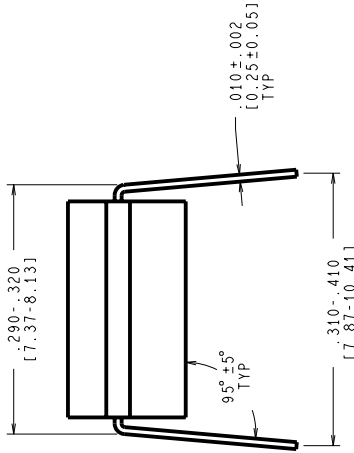
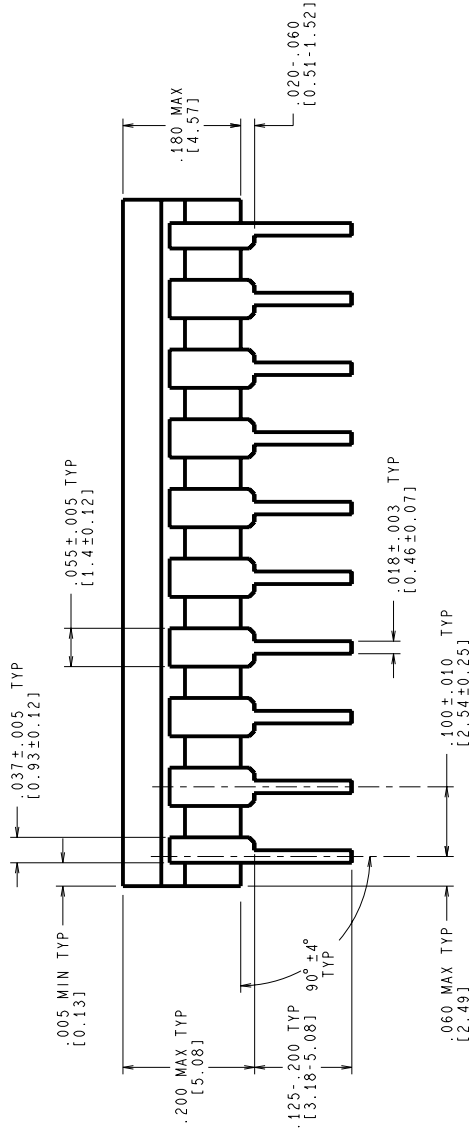
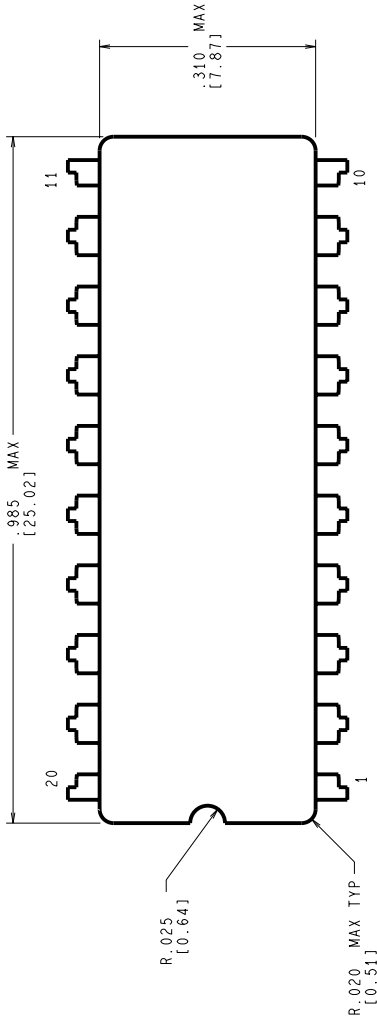
- NOTES: UNLESS OTHERWISE SPECIFIED.
- LEAD FINISH TO BE ONE OF THE FOLLOWING:

- 50 MICRONS/12.7 MICROMETERS MINIMUM GOLD PLATING OVER 50-350 MICRONS/1.27-8.89 MICROMETERS NICKEL.
 - SOLDER DIP.
SOLDER THICKNESS PER LATEST REVISION OF MIL-STD-1835.
- CORNER PADS MAY HAVE A 45° X $.020$ IN/0.51mm MAXIMUM CHAMFER TO ACCOMPLISH THE .015 IN/0.38mm DIMENSION.
 - REFERENCE JEDEC REGISTRATION MS-004, VARIATION CB, DATED 7/90.

MIL/AERO
CONFIGURATION CONTROL

APPROVALS		DATE	NATIONAL SEMICONDUCTOR CORPORATION	
DESIGN	Deayne Grady	02/10/94	2500 Semiconductor Drive, Santa Clara, CA 95052-8090	
ESTG	CHK.		LEADLESS CHIP CARRIER, TYPE C, 20 TERMINAL	
ENGR	CHK.			
APPROVAL				
PROJECTION			SCALE	SIZE
			N/A	C
			DO NOT SCALE	DRAWING
			MKT-E20A	REV
				E
				SHEET 1 of 1

REVISIONS			
LTR	DESCRIPTION	E.C.N.	DATE
N	REVISE AND REDRAW PER CURRENT STANDARD: UPDATE TITLE & MIL/AERO STAMP.	11596	03/27/1997
			MS/



CONTROLLING DIMENSION IS INCH
VALUES IN [] ARE MILLIMETERS

NOTES: UNLESS OTHERWISE SPECIFIED

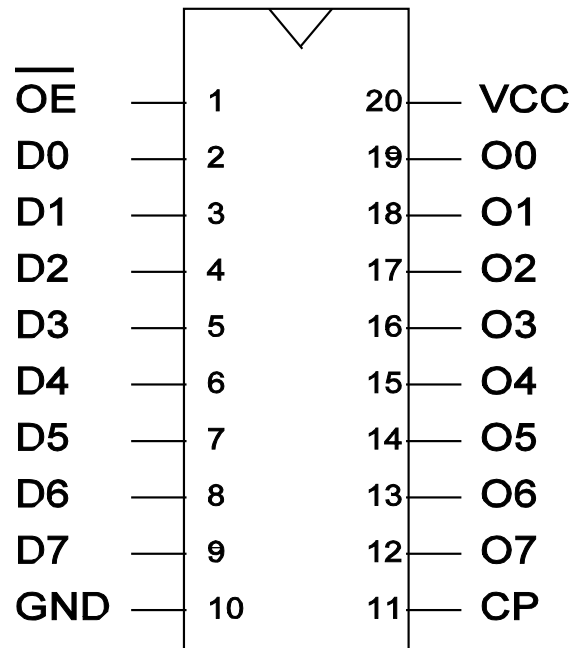
1. LEAD FINISH TO BE ONE OF THE FOLLOWING:
 - a. 200 MICRONS/ 5.08 MICROMETERS MINIMUM SOLDER MEASURED AT THE CREST OF THE MAJOR FLATS.
 - b. 200 TO 800 MICRONS/ 5.08 TO 20.32 MICROMETERS TIN PLATE OVER 50 TO 300 MICRONS/ 1.27 TO 7.62 MICROMETERS NICKEL UNDERPLATE OR BASIS METAL.
 - c. 50 TO 100 MICRONS/ 1.27 TO 2.54 MICROMETERS GOLD OVER 50 TO 350 MICRONS/ 1.27 TO 8.89 MICROMETERS NICKEL UNDERPLATE.
2. NO JEDEC REGISTRATION AS OF 03/27/1997.

MIL-PRF-38535
CONFIGURATION CONTROL

APPROVALS	DATE	National Semiconductor			
DRW: MARYA SUCHY	03/27/1997	2000 Semiconductor dr., Santa Clara, CA 95052-8000			
EST: CHK.		CERDIP, 20 LEAD, .300 CENTERS			
ENGR: CHK.					
PROJECTION		SCALE	SIZE	DRAWING NUMBER	REV.
		N/A	C	(SC)MKT-J20A	N
		DO NOT SCALE		DRAWING	SHEET 1 of 1

CONNECTION DIAGRAM

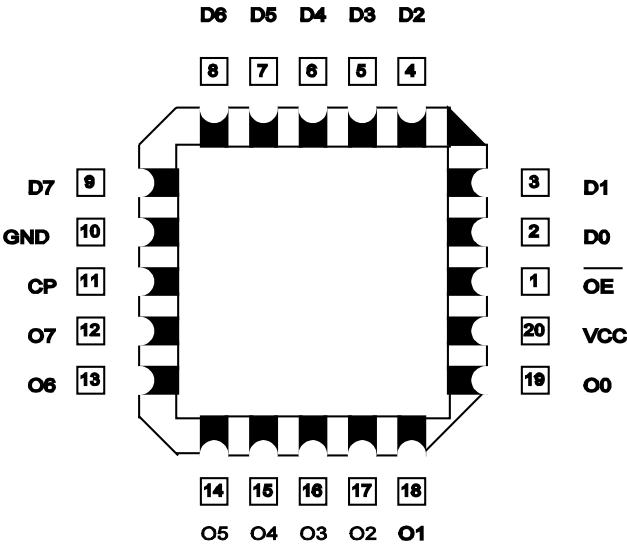
54ABT574



CDIP & FLATPACK PINOUT
(DWG # P000025A)

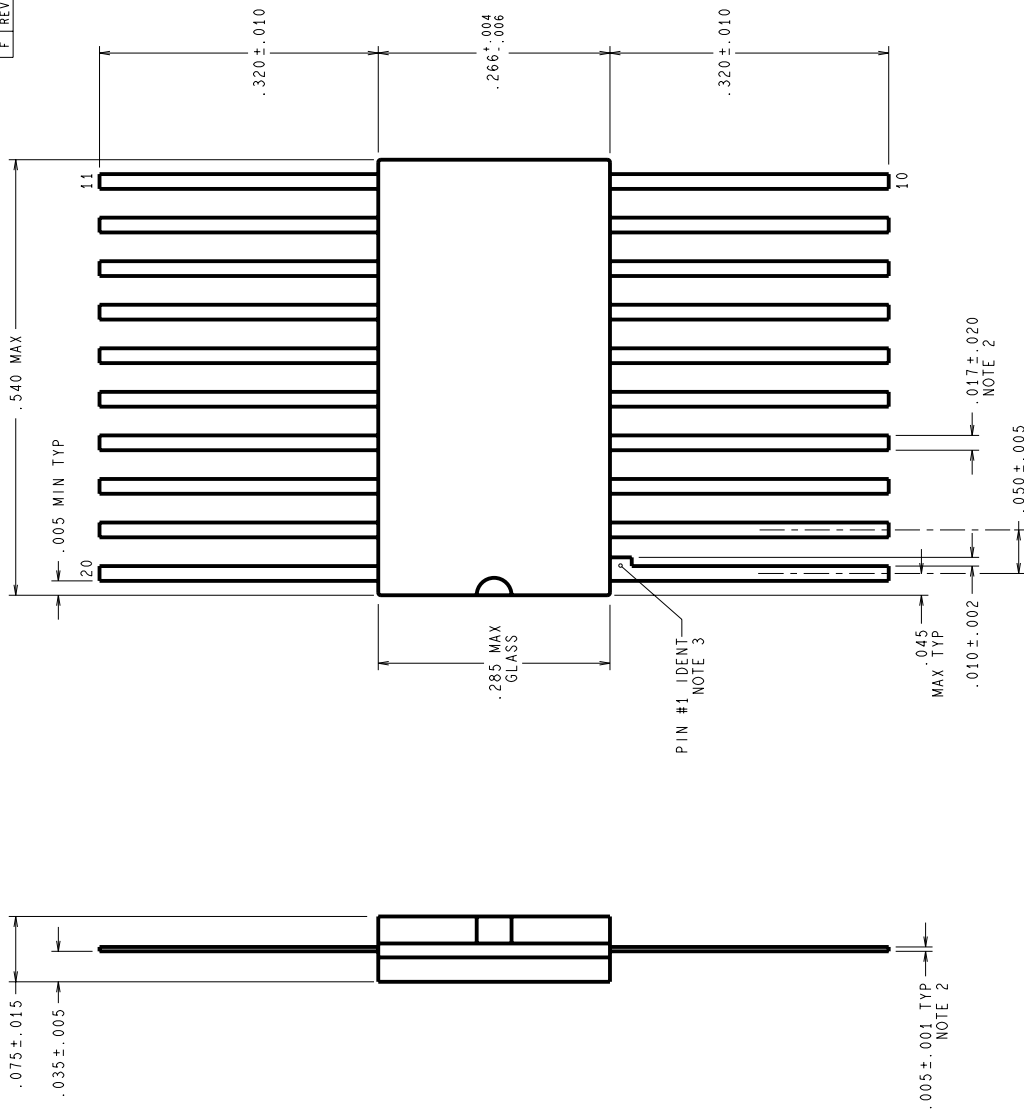
CONNECTION DIAGRAM

54ABT574



CERAMIC LEADLESS PINOUT

(DWG # P000026A)



NOTES: UNLESS OTHERWISE SPECIFIED.

1. LEAD FINISH: SOLDER DIPPED WITH Sn60 OR Sn63. SOLDER CONFORMING TO MIL-M-38510 TO A MINIMUM THICKNESS OF 200 MICROINCHES. SOLDER MAY BE APPLIED OVER LEAD BASIS METAL OR Sn PLATE.
2. MAXIMUM LIMIT MAY BE INCREASED BY .003 INCHES AFTER LEAD FINISH APPLIED.
3. LEAD 1 IDENTIFICATION SHALL BE:
a) A NOTCH OR OTHER MARK WITHIN THIS AREA
b) A TAB ON LEAD 1, EITHER SIDE
4. NO JEDEC REGISTRATION AS OF 02/70/94.

APPROVALS		DATE	 National Semiconductor 2800 Semiconductor dr., Santa Clara, CA 95052-8000 CERPACK, 20 LEAD			
DESIGN		07/28/94				
DRWG. CHK.						
ENGR. CHK.						
 PROJECTION			SCALE	SIZE	DRAWING NUMBER	REV
			N/A	C	MKT-W20A	F
			DO NOT SCALE	DRAWING	SHEET 1 of 1	

Revision History

Rev	ECN #	Rel Date	Originator	Changes
0B0	M0001581	10/14/98	Bill Petcher	Changed MDS MN54ABT574-X REV 0A0 to MN54ABT574-X REV 0B0